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December 2013

FDP52N20 / FDPF52N20T

N-Channel UniFETTM MOSFET 200 V, 52 A, (- $m\Omega$

Features

- R $_{DS(on)}$ = 41 m Ω (Typ.) @ V_{GS} = 10 V, I_{D} = 26 A
- Low Gate Charge (Typ. 49 nC)
- Low C_{RSS} (Typ. 66 pF)
- · 100% Avalanche Tested
- · RoHS Compliant

Applications

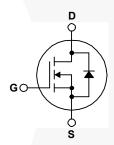
- PDP TV
- Lighting
- · Uninterruptible Power Supply
- AC-DC Power Supply

Description

UniFETTM MOSFET is Fairchild Semiconductor's high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.







MOSFET Maximum Ratings T_C = 25°C unless otherwise noted.

Symbol		Parameter		FDP52N20	FDPF52N20T	Unit
V _{DSS}	Drain to Source Voltage			2	V	
V_{GSS}	Gate to Source Voltage			±30		V
	Drain Current	- Continuous (T _C = 25°C)		52	52*	۸
ID	DrainCurrent	- Continuous (T _C = 100°C)		33	33*	Α
I _{DM}	Drain Current - Pulsed		(Note 1)	208 208*		Α
E _{AS}	Single Pulsed Avalanche Energy		(Note 2)	2520		mJ
I _{AR}	Avalanche Current		(Note 1)	52		Α
E _{AR}	Repetitive Avalanche Energy		(Note 1)	35.7		mJ
dv/dt	Peak Diode Recovery dv/dt		(Note 3)	4.5		V/ns
Б	Dower Discipation	$(T_C = 25^{\circ}C)$		357	38.5	W
P_{D}	Power Dissipation - Derate above 25°C			2.86	0.3	W/°C
T _J , T _{STG}	Operating and Storage Temperature Range			-55 to +150		°C
TL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 Seconds			300		°C

^{*}Drain current limited by maximum junction temperature

Thermal Characteristics

Symbol	Parameter	FDP52N20	FDPF52N20T	Unit
$R_{ heta JC}$	Thermal Resistance, Junction to Case, Max.	0.35	3.3	°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient, Max.	62.5	62.5	*C/VV

Package Marking and Ordering Information

Part Number	Top Mark	Package	Packing Method	Reel Size	Tape Width	Quantity
FDP52N20	FDP52N20	TO-220	Tube	N/A	N/A	50 units
FDPF52N20T	FDPF52N20T	TO-220F	Tube	N/A	N/A	50 units

Test Conditions

Min.

Тур.

Max.

Unit

Electrical Characteristics $T_C = 25^{\circ}C$ unless otherwise noted. **Parameter**

Off Chara	octeristics					
BV _{DSS}	Drain to Source Breakdown Voltage	$I_D = 250 \mu\text{A}, V_{GS} = 0 \text{V}, T_J = 25^{\circ}\text{C}$	200	-	-	V
ΔBV _{DSS} / ΔΤ _J	Breakdown Voltage Temperature Coefficient	I_D = 250 μA, Referenced to 25°C	-	0.2	-	V/°C
	Zero Gate Voltage Drain Current	V _{DS} = 200 V, V _{GS} = 0 V	-	-	1	
IDSS	Zero Gate voltage Drain Current	$V_{DS} = 160 \text{ V}, T_{C} = 125^{\circ}\text{C}$	-	-	10	μΑ
I _{GSS}	Gate to Body Leakage Current	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$	-	-	±100	nA

On Characteristics

Symbol

V _{GS(th)}	Gate Threshold Voltage	$V_{GS} = V_{DS}, I_D = 250 \mu A$	3.0	-	5.0	V
R _{DS(on)}	Static Drain to Source On Resistance	$V_{GS} = 10 \text{ V}, I_D = 26 \text{ A}$	-	0.041	0.049	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40 \text{ V}, I_{D} = 26 \text{ A}$	-	35	-	Ø

Dynamic Characteristics

C _{iss}	Input Capacitance	V 25 V V 0 V	-	2230	2900	pF
C _{oss}	Output Capacitance	$V_{DS} = 25 \text{ V}, V_{GS} = 0 \text{ V}$ f = 1 MHz		540	700	pF
C _{rss}	Reverse Transfer Capacitance	1 - 1 1/11/12	-	66	100	pF
Q _{g(tot)}	Total Gate Charge at 10V		-\	49	63	nC
Q _{gs}	Gate to Source Gate Charge	$V_{DS} = 160 \text{ V}, I_{D} = 52 \text{ A}$	-	19	-	nC
Q _{gd}	Gate to Drain "Miller" Charge	$V_{GS} = 10 \text{ V}$ (Note 4)	-	24	-	nC

Switching Characteristics

t _{d(on)}	Turn-On Delay Time		-	53	115	ns
t _r		$V_{DD} = 100 \text{ V}, I_D = 20 \text{ A}$	-	175	359	ns
t _{d(off)}	Turn-Off Delay Time	$R_G = 25 \Omega$	-	48	107	ns
t _f	Turn-Off Fall Time	(Note 4)	-	29	68	ns

Drain-Source Diode Characteristics

I _S	Maximum Continuous Drain to Source Diode Forward Current			-	52	Α
I _{SM}	Maximum Pulsed Drain to Source Diode Forward Current		-	-	204	Α
V_{SD}	Drain to Source Diode Forward Voltage	V _{GS} = 0 V, I _{SD} = 52 A	-	- y	1.5	V
t _{rr}	Reverse Recovery Time	V _{GS} = 0 V, I _{SD} = 52 A	-	162	-	ns
Q _{rr}	Reverse Recovery Charge dI _F /dt = 100 A/μs		-	1.3	-	μС

- 1: Repetitive rating: pulse-width limited by maximum junction temperature. 2: L = 1.4 mH, I_{AS} = 52 A, V_{DD} = 50 V, R_G = 25 Ω , starting T_J = 25°C.
- 3: $I_{SD} \le 52$ A, di/dt ≤ 200 A/ μs , $V_{DD} \le BV_{DSS}$, starting T_J = 25°C.
- 4: Essentially independent of operating temperature typical characteristics.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

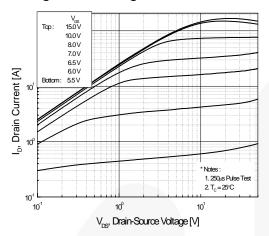


Figure 3. On-Resistance Variation vs.

Drain Current and Gate Voltage

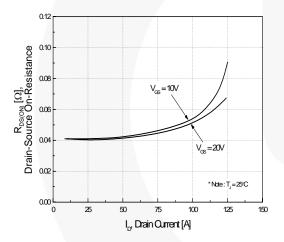


Figure 5. Capacitance Characteristics

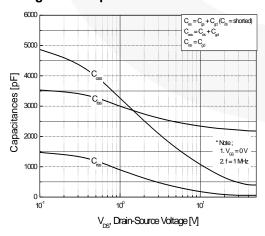


Figure 2. Transfer Characteristics

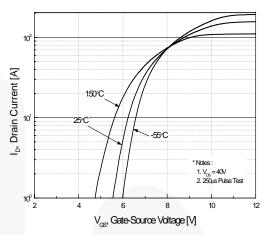


Figure 4. Body Diode Forward Voltage Variation vs. Source Current and Temperature

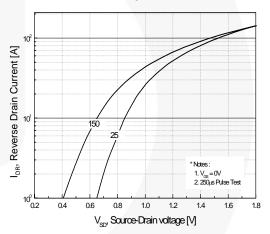
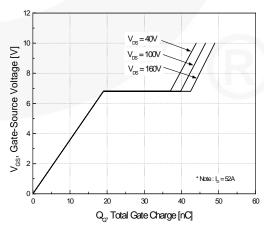


Figure 6. Gate Charge Characteristics



Typical Performance Characteristics (Continued)

Figure 7. Breakdown Voltage Variation vs. Temperature

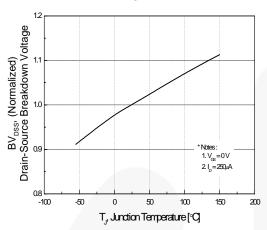


Figure 9-1. Maximum Safe Operating Area - FDP52N20

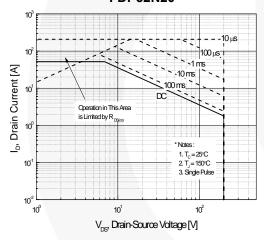


Figure 10. Maximum Drain Current

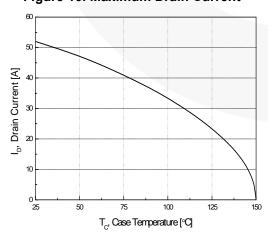


Figure 8. On-Resistance Variation vs. Temperature

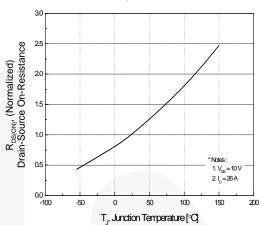
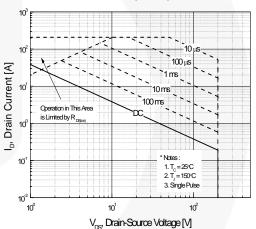


Figure 9-2. Maximum Safe Operating Area - FDPF52N20T



Typical Performance Characteristics (Continued)

Figure 11-1. Transient Thermal Response Curve - FDP52N20

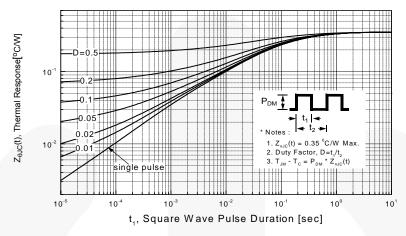
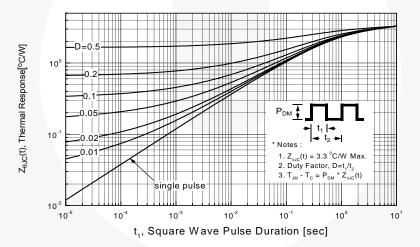


Figure 11-2. Transient Thermal Response Curve - FDPF52N20T



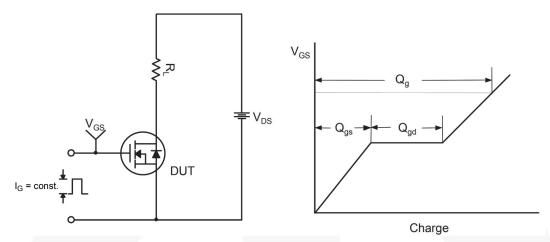


Figure 12. Gate Charge Test Circuit & Waveform

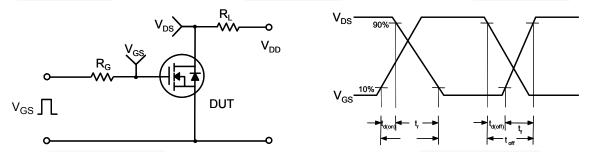


Figure 13. Resistive Switching Test Circuit & Waveforms

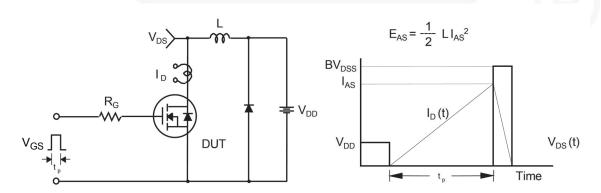


Figure 14. Unclamped Inductive Switching Test Circuit & Waveforms

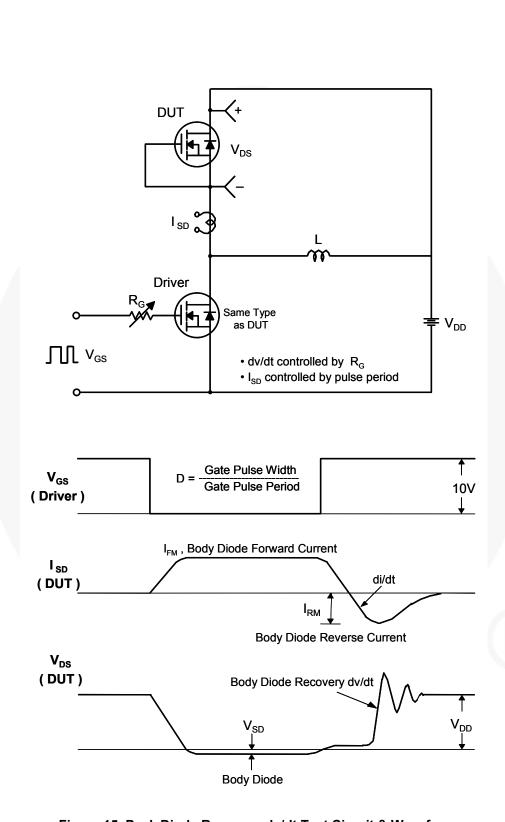


Figure 15. Peak Diode Recovery dv/dt Test Circuit & Waveforms

Mechanical Dimensions

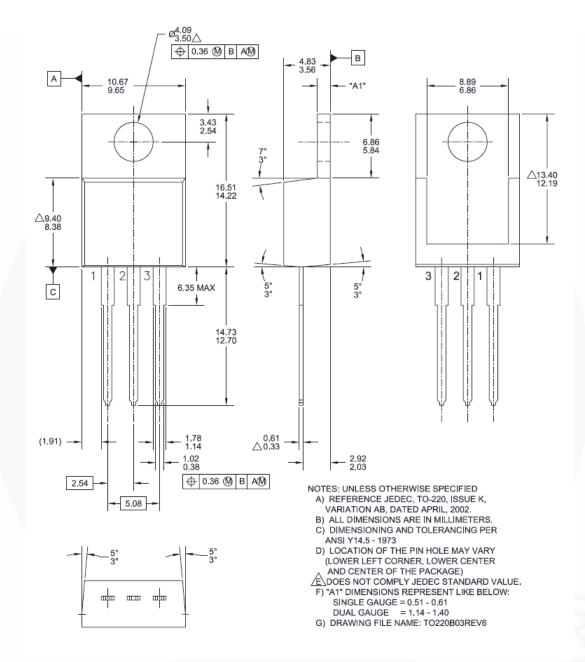


Figure 16. TO-220, Molded, 3-Lead, Jedec Variation AB

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Mechanical Dimensions

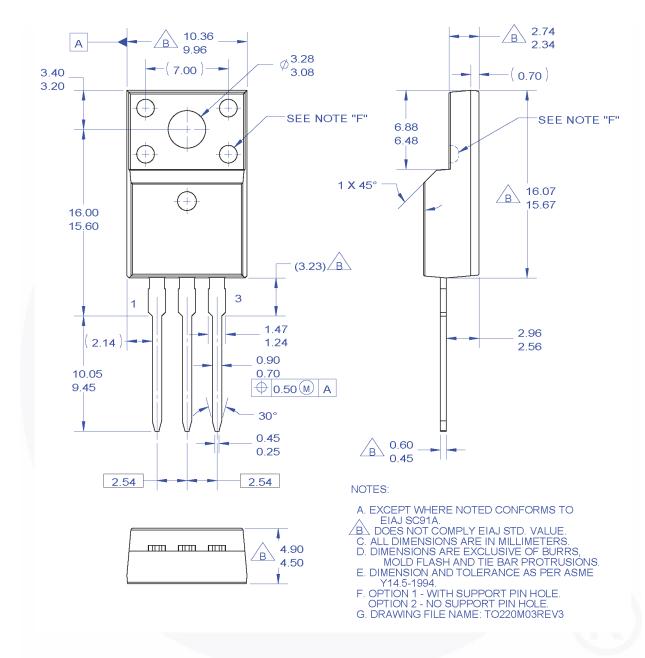


Figure 17. TO220, Molded, 3-Lead, Full Pack, EIAJ SC91, Straight Lead

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